

International
IR Rectifier

100BGQ030
100BGQ030J

SCHOTTKY RECTIFIER

100 Amp

Major Ratings and Characteristics

Characteristics	100BGQ030	Units
$I_{F(AV)}$ Rectangular waveform @ T_C	100	A
I_{DC} Maximum	141	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 5 \mu s$ sine	4500	A
V_F @ 100Apk typical @ T_J	0.48	V
T_J range	-55 to 150	°C

Description/Features

The NEW 100BGQ030 Schottky rectifier has been optimized for ultra low forward voltage drop specifically for low voltage output in high current AC/DC power supplies.

The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

- 150°C T_J operation
- High Frequency Operation
- Ultra low forward voltage drop
- Continuous High Current operation
- Guard ring for enhanced ruggedness and long term reliability
- **PowIRtab™ package**

Case Styles

100BGQ030



100BGQ030J



100BGQ030, 100BGQ030J

PD-20996 rev. D 11/99

International
IR Rectifier

Voltage Ratings

Part number	100BGQ030
V_R Max. DC Reverse Voltage (V)	30
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	100BGQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	100	A	50% duty cycle @ $T_C = 110^\circ\text{C}$, rectangular wave form
$I_{F(RMS)}$ RMS Forward Current	141	A	$T_C = 107^\circ\text{C}$
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	4500	A	5 μs Sine or 3 μs Rect. pulse
	850		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	36	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 8\text{ Amps}$, $L = 1.12\text{ mH}$
I_{AR} Repetitive Avalanche Current	8	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	100BGQ		Units	Conditions	
	Typ.	Max.			
V_{FM} Forward Voltage Drop (1) (2)	0.46	0.48	V	@ 50A	$T_J = 25^\circ\text{C}$
	0.55	0.58	V	@ 100A	
	0.35	0.37	V	@ 50A	$T_J = 150^\circ\text{C}$
	0.48	0.51	V	@ 100A	
I_{RM} Reverse Leakage Current (1)	0.6	2.4	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_R$
	260	460	mA	$T_J = 125^\circ\text{C}$	
	80	160	mA	$T_J = 125^\circ\text{C}$	$V_R = 15\text{V}$
	800	1100	mA	$T_J = 150^\circ\text{C}$	$V_R = 30\text{V}$
$V_{F(TO)}$ Threshold Voltage	0.252		V	$T_J = T_J \text{ max.}$	
r_t Forward Slope Resistance	2.4		m Ω		
C_T Max. Junction Capacitance	3800		pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C	
L_S Typical Series Inductance	3.5		nH	Measured from tab to mounting plane	
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000		V/ μs		

(1) Pulse Width < 300 μs , Duty Cycle < 2%

(2) $V_{FM} = V_{F(TO)} + r_t \times I_F$

Thermal-Mechanical Specifications

Parameters	100BGQ	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 150	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case	0.50	$^\circ\text{C/W}$	DC operation
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.20	$^\circ\text{C/W}$	Mounting surface, smooth and greased
wt Approximate Weight	5(0.18)	g(oz.)	
T Mounting Torque	Min.	1.2(10)	N*m (lbf-in)
	Max.	2.4(20)	
Case Style	PowIRtab™		

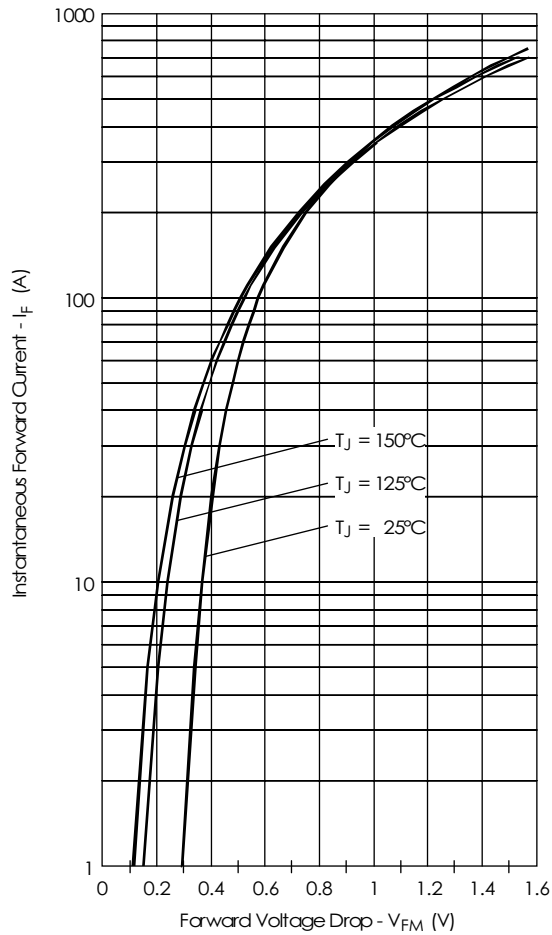


Fig. 1 - Maximum Forward Voltage Drop Characteristics

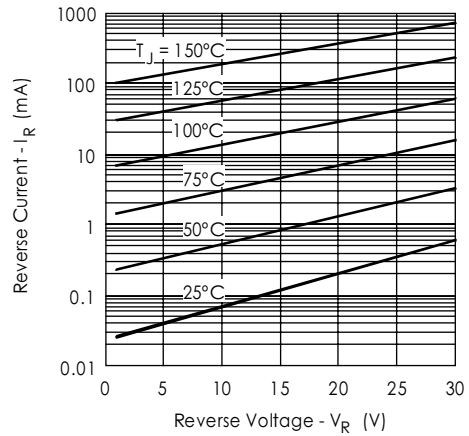


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

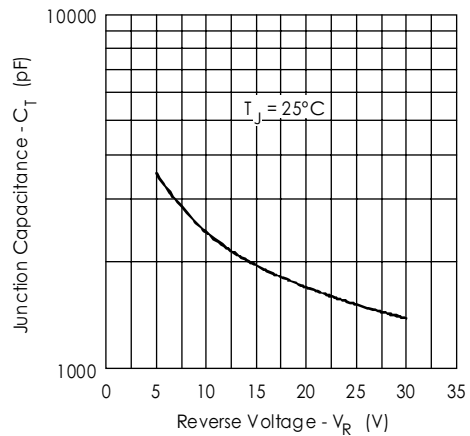


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

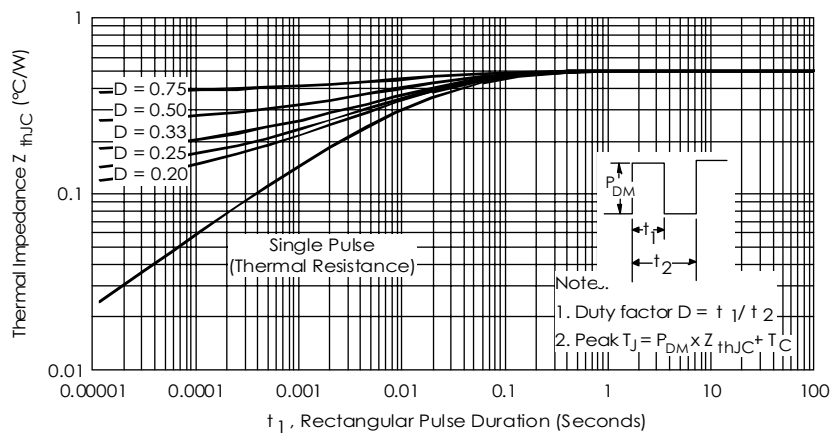


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

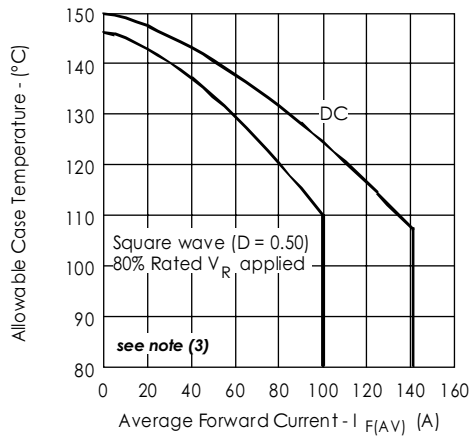


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

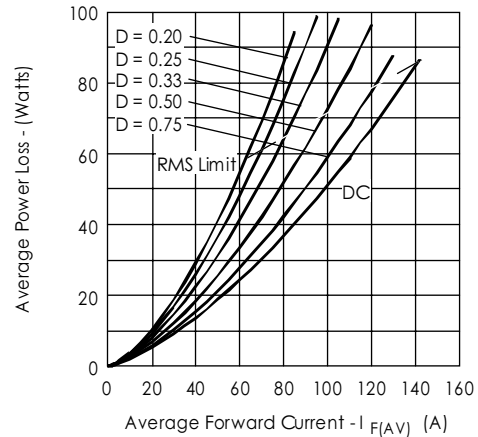


Fig. 6 - Forward Power Loss Characteristics

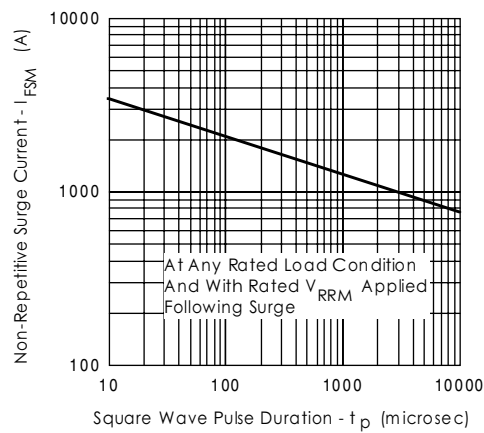


Fig. 7 - Maximum Non-Repetitive Surge Current

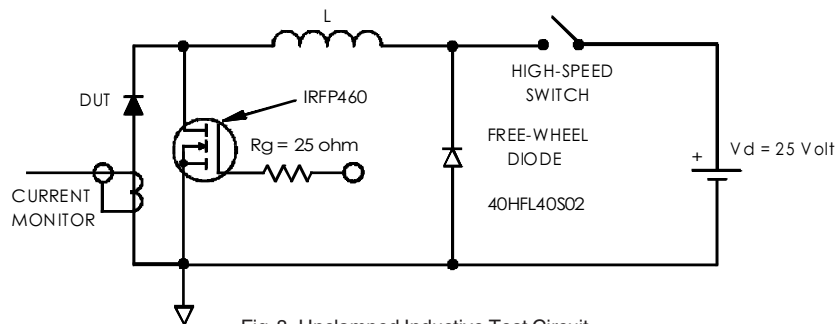


Fig. 8 - Unclamped Inductive Test Circuit

(3) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

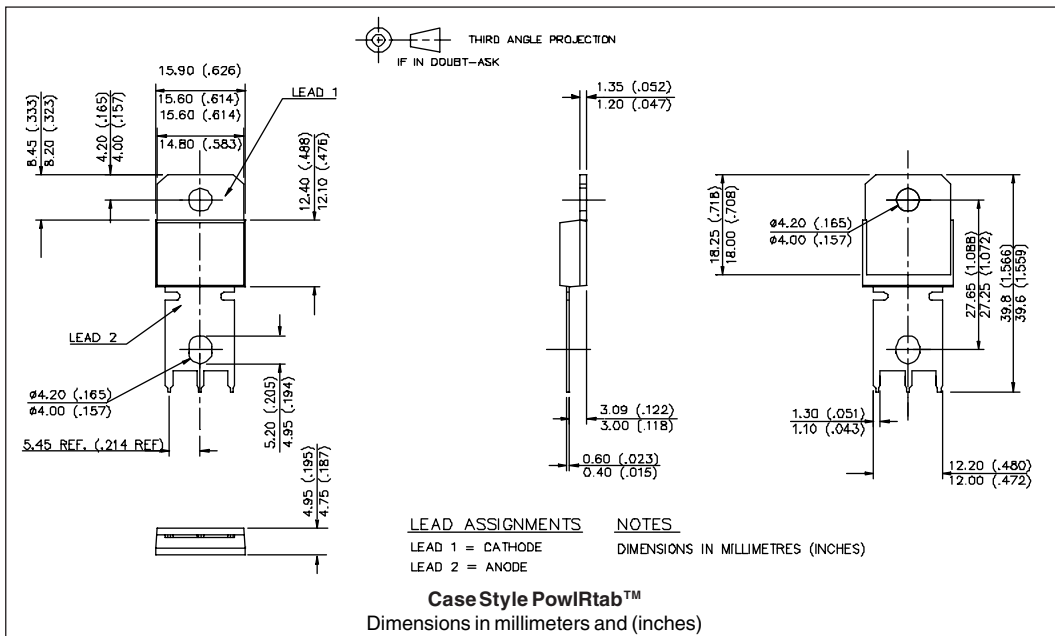
P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

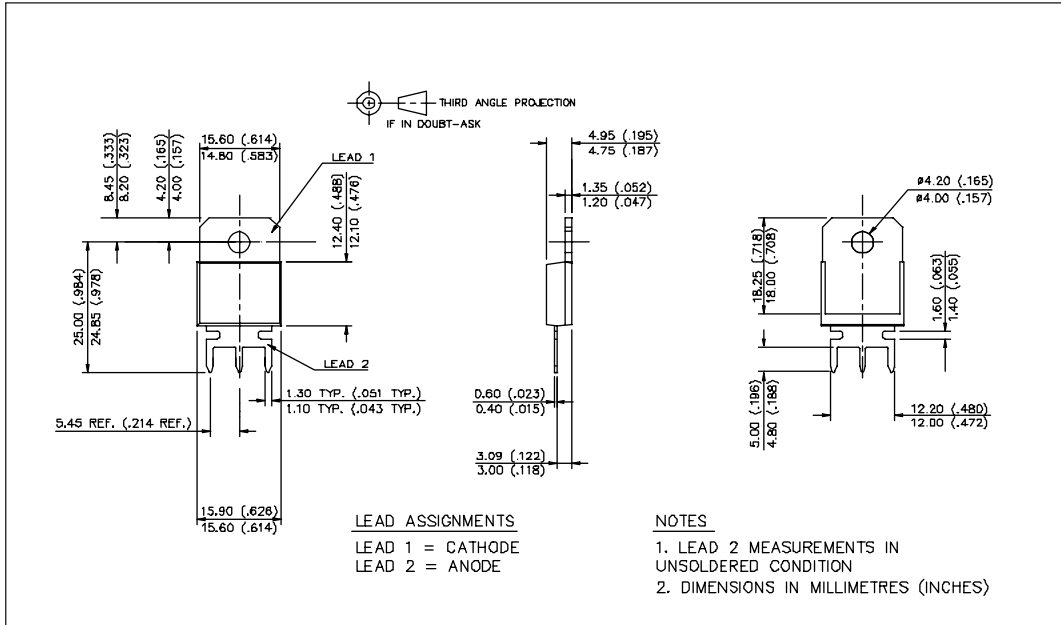
Ordering Information Table

Device Code			
100	BGQ	030	J
①	②	③	④
1	-	Current Rating	
2	-	Essential Part Number	
3	-	Voltage code: Code = V_{RRM}	
4	-	none = PowlRtab™ standard	
	J	= Short Lead Version	

Outline Table



Outline Table



This model has been developed by
 Wizard SPICE MODEL GENERATOR(1999)
 (International Rectifier Corporation)
 contains Proprietary Information

SPICE Model Diode is composed by a
 simple diode plus paralalled VCG2T

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.SUBCKT 100bgq30 ANO CAT
D1 ANO 1 DMOD (0.24359)
*Define diode model
.MODEL DMOD D(IS=1.07823961851333E-04A,N=1.0394338412755,BV=30V,
+IBV=0.125061622097042A,RS=0.000316667,CJO=2.88578786999339E-08,
+VJ=1.30385147429609,XTI=2,EG=0.697469117594151)
*****
* Implementation of VCG2T
VX 1 2 DC 0V
R1 2 CAT TRES 1E-6
.MODEL TRES RES(R=1,TC1=6.48759701319255)
GP1 ANO CAT VALUE={-ABS(I(VX))*(EXP(((((-2.690102E-03/
6.487597)*((V(2,CAT)*1E6)/(I(VX)+1E-6)-1))+1)*9.995116E-02*ABS(V(ANO,CAT)))-1)}
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.ENDS100bgq30

Thermal Model Subcircuit

.SUBCKT 100bgq30T 5 1

CTHERM1	5	4	3.02E+3
CTHERM2	4	3	4.96E+1
CTHERM3	3	2	3.84E+4
CTHERM4	2	1	3.02E+6

RTHERM1	5	4	1.02E-1
RTHERM2	4	3	3.83E-1
RTHERM3	3	2	6.09E-2
RTHERM4	2	1	1.00E-5

.ENDS100bgq30T